TOSHIBA CMOS Digital Integrated Circuit Silicon Monolithic

## TC74AC245P,TC74AC245F,TC74AC245FW,TC74AC245FT TC74AC640P,TC74AC640F,TC74AC640FW,TC74AC640FT

Octal Bus Transceiver

TC74AC245P/F/FW/FT 3-State, Non-Inverting TC74AC640P/F/FW/FT 3-State, Inverting

The TC74AC245, 640 are advanced high speed CMOS OCTAL BUS TRANSCEIVERs fabricated with silicon gate and double-layer metal wiring C<sup>2</sup>MOS technology.

They achieve the high speed operation similar to equivalent Bipolar Schottky TTL while maintaining the CMOS low power dissipation.

They are intended for two-way asynchronous communication between data busses. The direction of data transmission is determined by the level of the DIR input.

The enable input ( $\overline{G}$ ) can be used to disable the device so that the busses are effectively isolated.

All inputs are equipped with protection circuits against static discharge or transient excess voltage.

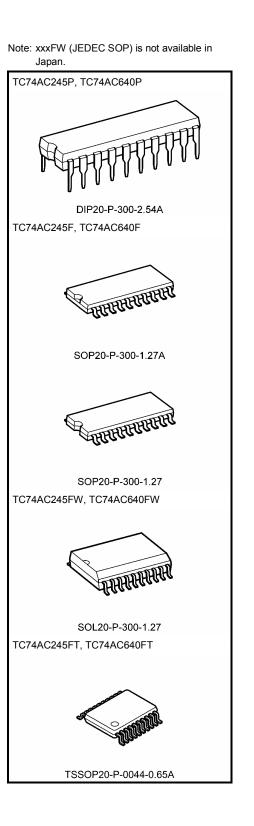
## Features (Note 1)(Note 2)

- High speed:  $t_{pd} = 3.9 \text{ ns}$  (typ.) at  $V_{CC} = 5 \text{ V}$
- Low power dissipation:  $I_{CC}$  = 8  $\mu A$  (max) at Ta = 25°C
- High noise immunity:  $V_{NIH} = V_{NIL} = 28\% V_{CC}$  (min)
- Symmetrical output impedance: |IOH| = IOL = 24 mA (min)Capability of driving 50  $\Omega$  transmission lines.
- Balanced propagation delays:  $t_pLH \simeq t_pHL$
- Wide operating voltage range: VCC (opr) = 2 V to 5.5 V
- Pin and function compatible with 74F245/640

Note 1: Do not apply a signal to any bus terminal when it is in the output mode. Damage may result.

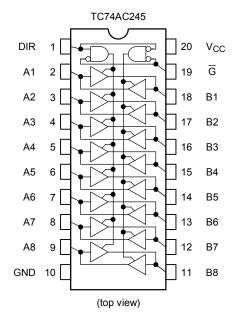
Note 2: All floating (high impedance) bus terminals must have their input levels fixed by means of pull up or pull down resistors.

Weight	
DIP20-P-300-2.54A	: 1.30 g (typ.)
SOP20-P-300-1.27A	: 0.22 g (typ.)
SOP20-P-300-1.27	: 0.22 g (typ.)
SOL20-P-300-1.27	: 0.46 g (typ.)
TSSOP20-P-0044-0.65A	: 0.08 g (typ.)

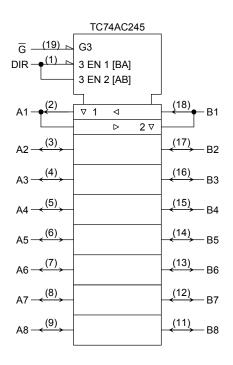


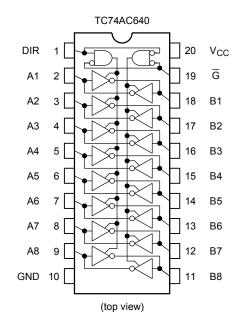
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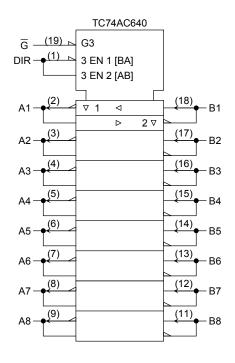
## **Pin Assignment**











#### Truth Table

Inp	outs	Fund	ction	Out	AC640		
G	DIR	DIR A Bus B Bus		AC245	AC640		
L	L	Output	Input	A = B	$A = \overline{B}$		
L	Н	Input	Output	B = A	B = Ā		
Н	Х	2	7	Z	Z		

X: Don't care

Z: High impedance

#### Absolute Maximum Ratings (Note 1)

Characteristics	Symbol	Rating	Unit
Supply voltage range	V <sub>CC</sub>	-0.5 to 7.0	V
DC input voltage	V <sub>IN</sub>	-0.5 to V <sub>CC</sub> + 0.5	V
DC output voltage	V <sub>OUT</sub>	-0.5 to V <sub>CC</sub> + 0.5	V
Input diode current	Iк	±20	mA
Output diode current	I <sub>OK</sub>	±50	mA
DC output current	IOUT	±50	mA
DC V <sub>CC</sub> /ground current	Icc	±200	mA
Power dissipation	PD	500 (DIP) (Note 2)/180 (SOP/TSSOP)	mW
Storage temperature	T <sub>stg</sub>	-65 to 150	°C

Note1: Exceeding any of the absolute maximum ratings, even briefly, lead to deterioration in IC performance or even destruction.

Note2: 500 mW in the range of Ta = −40°C to 65°C. From Ta = 65°C to 85°C a derating factor of −10 mW/°C should be applied up to 300 mW.

#### **Recommended Operating Conditions (Note)**

Characteristics	Symbol	Rating	Unit
Supply voltage	V <sub>CC</sub>	2.0 to 5.5	V
Input voltage	VIN	0 to V <sub>CC</sub>	V
Output voltage	V <sub>OUT</sub>	0 to V <sub>CC</sub>	V
Operating temperature	T <sub>opr</sub>	-40 to 85	°C
Input rise and fall time	dt/dV	0 to 100 (V <sub>CC</sub> = 3.3 ± 0.3 V)	ns/V
		0 to 20 (V <sub>CC</sub> = 5 ± 0.5 V)	

Note: The recommended operating conditions are required to ensure the normal operation of the device. Unused inputs must be tied to either VCC or GND.

## **Electrical Characteristics**

#### **DC Characteristics**

Characteristics	Symbol	Test Condition		Ta = 25°C			Ta = −40 to 85°C		Unit		
Unaracteristics	Gymbol				V <sub>CC</sub> (V)	Min	Тур.	Max	Min	Max	Onit
					2.0	1.50	_	_	1.50		
High-level input voltage	VIH	—		3.0	2.10	_	—	2.10	—	V	
					5.5	3.85	_	—	3.85	—	
					2.0	_	_	0.50	_	0.50	0.50
Low-level input voltage	VIL		_		3.0	—	_	0.90	_	0.90	V
					5.5	-	—	1.65	—	1.65	
					2.0	1.9	2.0		1.9	_	
	V <sub>OH</sub>		I <sub>OH</sub> = −50 µA		3.0	2.9	3.0	—	2.9	—	
High-level output		V <sub>IN</sub> = V <sub>IH</sub> or V <sub>IL</sub>			4.5	4.4	4.5	—	4.4	—	V
voltage			I <sub>OH</sub> = -4 mA		3.0	2.58	_	_	2.48	-	
			I <sub>OH</sub> = −24 mA		4.5	3.94	—	—	3.80	—	
			I <sub>OH</sub> = −75 mA	(Note)	5.5	-	—	-	3.85	—	
					2.0		0.0	0.1	—	0.1	v
		V <sub>IN</sub> = V <sub>IH</sub> or	I <sub>OL</sub> = 50 μA		3.0	—	0.0	0.1	—	0.1	
Low-level output	V <sub>OL</sub>				4.5	-	0.0	0.1	—	0.1	
voltage	VOL	VIL	I <sub>OL</sub> = 12 mA		3.0		_	0.36	—	0.44	v
			I <sub>OL</sub> = 24 mA		4.5	—	—	0.36	—	0.44	
			I <sub>OL</sub> = 75 mA	(Note)	5.5	—	—	—	—	1.65	
3-state output off-state current	I <sub>OZ</sub>	$V_{IN} = V_{IH} \text{ or } V_{IL}$ $V_{OUT} = V_{CC} \text{ or } GND$		5.5	_	_	±0.5	_	±5.0	μA	
Input leakage current	I <sub>IN</sub>	V <sub>IN</sub> = V <sub>CC</sub> or GND		5.5	-	_	±0.1	—	±1.0	μA	
Quiescent supply current	ICC	$V_{IN} = V_{CC}$ or GND		5.5	_	_	8.0	_	80.0	μA	

Note: This spec indicates the capability of driving 50  $\Omega$  transmission lines.

One output should be tested at a time for a 10 ms maximum duration.

#### AC Characteristics (C<sub>L</sub> = 50 pF, R<sub>L</sub> = 500 $\Omega$ , input: t<sub>r</sub> = t<sub>f</sub> = 3 ns)

Characteristics Symbol		Test Condition		Ta = 25°C			Ta = −40 to 85°C		Unit	
	- <b>)</b>		V <sub>CC</sub> (V)	Min	Тур.	Max	Min	Max		
Propagation delay	t <sub>pLH</sub>		3.3 ± 0.3	_	7.0	10.9	1.0	12.4	ns	
time (Note 2)	t <sub>pHL</sub>	—	$5.0 \pm 0.5$	—	5.0	7.5	1.0	8.5	115	
Propagation delay	t <sub>pLH</sub>		3.3 ± 0.3	_	6.4	10.0	1.0	11.4		
time (Note 3)	t <sub>pHL</sub>	—	5.0 ± 0.5	—	4.8	7.0	1.0	8.0	ns	
Output anabla time	t <sub>pZL</sub>		3.3 ± 0.3	_	9.3	15.3	1.0	17.4	ns	
Output enable time	t <sub>pZH</sub>	—	$5.0 \pm 0.5$	—	7.1	10.5	1.0	12.0	115	
Output disable time	t <sub>pLZ</sub>		3.3 ± 0.3	_	7.1	11.4	1.0	13.0	ns	
Output disable time	t <sub>pHZ</sub>	—	$5.0 \pm 0.5$	—	5.9	8.7	1.0	10.0	115	
Input capacitance	CIN	DIR, G		_	5	10	_	10	pF	
Bus input capacitance	C <sub>I/O</sub>	A <sub>n</sub> , Bn		_	13	_	_	_	pF	
Power dissipation	C <sub>PD</sub>	TC74AC245		_	38	_	_	_	_	
capacitance	(Note 1)	TC74AC640		_	36	_	_	_	рF	

Note 1: C<sub>PD</sub> is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

Average operating current can be obtained by the equation:

 $I_{CC (opr)} = C_{PD} \cdot V_{CC} \cdot f_{IN} \cdot I_{CC} / 8 (per bit)$ 

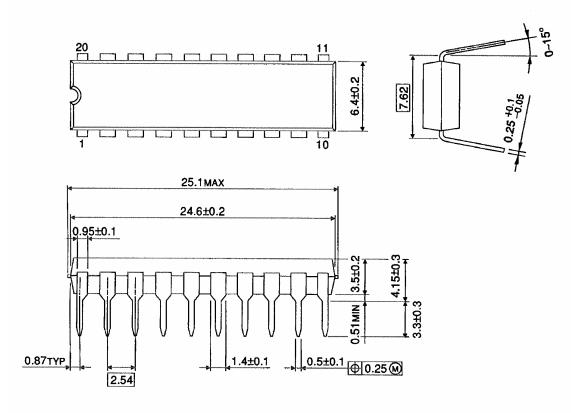
Note 2: For TC74AC245 only

Note 3: For TC74AC640 only

## Package Dimensions

DIP20-P-300-2.54A

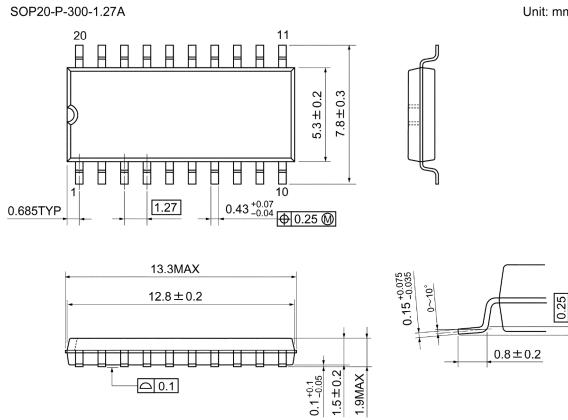
Unit : mm



Weight: 1.30 g (typ.)

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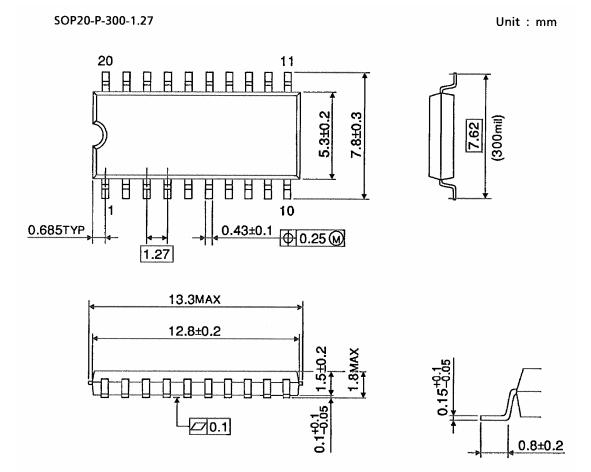
## **Package Dimensions**



Weight: 0.22 g (typ.)

Unit: mm

## Package Dimensions

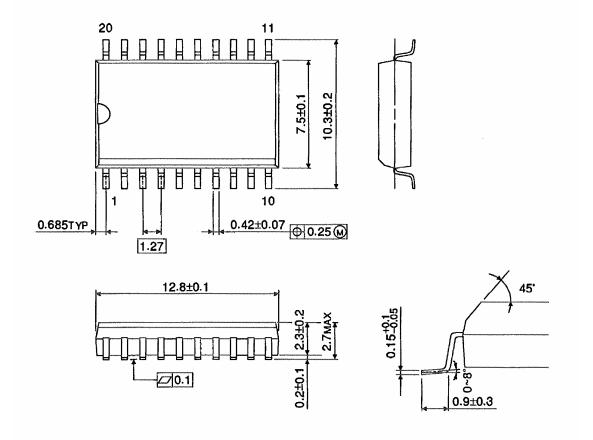


Weight: 0.22 g (typ.)

## Package Dimensions (Note)

SOL20-P-300-1.27

Unit : mm



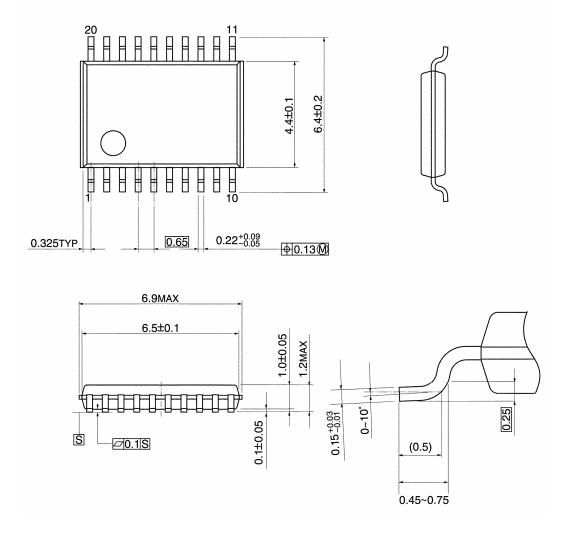
Note: This package is not available in Japan.

Weight: 0.46 g (typ.)

## Package Dimensions

TSSOP20-P-0044-0.65A

Unit: mm



Weight: 0.08 g (typ.)

Note: Lead (Pb)-Free Packages DIP20-P-300-2.54A SOP20-P-300-1.27A TSSOP20-P-0044-0.65A

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